

SILICON POWER TRANSISTOR

2SC3570

NPN SILICON TRIPLE DIFFUSED TRANSISTOR

FOR HIGH-VOLTAGE HIGH-SPEED SWITCHING

The 2SC3570 is a mold power transistor developed for high-voltage high-speed switching, and is ideal for use in drivers such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

FEATURES

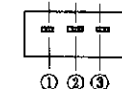
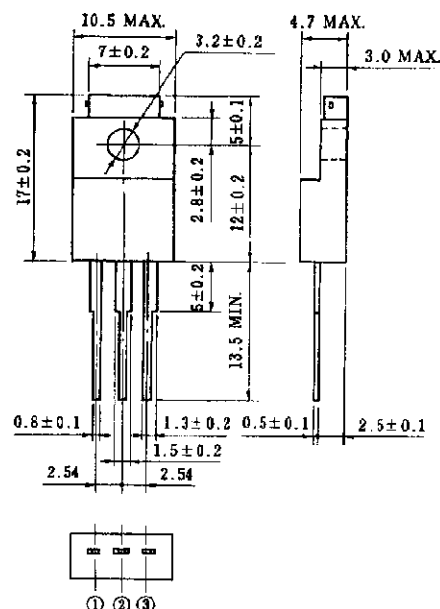
- Mold package that does not require an insulating board or insulation bushing
- Low collector saturation voltage:
 $V_{CE(sat)} = 1.0 \text{ V MAX. (@ } 2 \text{ A)}$
- Fast switching speed:
 $t_f \leq 0.7 \mu\text{s MAX. (@ } 2 \text{ A)}$
- Wide base reverse-bias SOA:
 $V_{CEX(SUS)} = 450 \text{ V MIN. (@ } 2 \text{ A)}$

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	500	V
Collector to emitter voltage	V_{CEO}	400	V
Emitter to base voltage	V_{EBO}	8.0	V
Collector current (DC)	$I_{C(DC)}$	5.0	A
Collector current (pulse)	$I_{C(pulse)}^*$	10	A
Base current (DC)	$I_{B(DC)}$	2.5	A
Total power dissipation	$P_T (T_c = 25^\circ\text{C})$	25	W
Total power dissipation	$P_T (T_a = 25^\circ\text{C})$	2.0	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

* $PW \leq 300 \mu\text{s}$, duty cycle $\leq 10\%$

PACKAGE DRAWING (UNIT: mm)



Electrode Connection

1. Base
2. Collector
3. Emitter

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

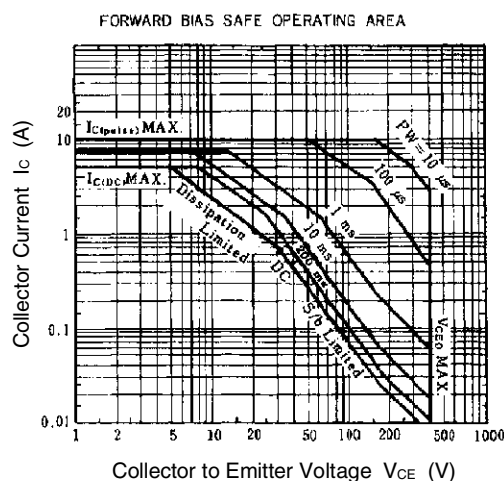
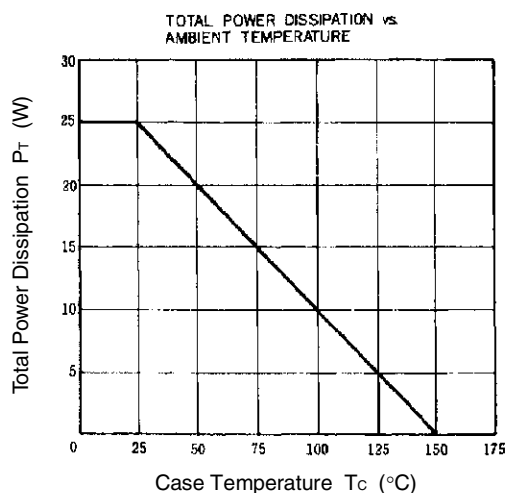
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	$V_{CEO(SUS)}$	$I_C = 2.0\text{ A}$, $I_{B1} = 0.4\text{ A}$, $L = 1\text{ mH}$	400			V
Collector to emitter voltage	$V_{CEX(SUS)1}$	$I_C = 2.0\text{ A}$, $I_{B1} = -I_{B2} = 0.4\text{ A}$, $L = 180\text{ }\mu\text{H}$, clamped	450			V
Collector to emitter voltage	$V_{CEX(SUS)2}$	$I_C = 4.0\text{ A}$, $I_{B1} = 0.8\text{ A}$, $-I_{B2} = 0.4\text{ A}$, $L = 180\text{ }\mu\text{H}$, clamped	400			V
Collector cutoff current	I_{CBO}	$V_{CB} = 400\text{ V}$, $I_E = 0$			10	μA
Collector cutoff current	I_{CER}	$V_{CE} = 400\text{ V}$, $R_{BE} = 51\text{ }\Omega$, $T_a = 125^\circ\text{C}$			1.0	mA
Collector cutoff current	I_{CEX1}	$V_{CE} = 400\text{ V}$, $V_{BE(OFF)} = -1.5\text{ V}$			10	μA
Collector cutoff current	I_{CEX2}	$V_{CE} = 400\text{ V}$, $V_{BE(OFF)} = -1.5\text{ V}$, $T_a = 125^\circ\text{C}$			1.0	mA
Emitter cutoff current	I_{EBO}	$V_{EB} = 5.0\text{ V}$, $I_C = 0$			10	μA
DC current gain	h_{FE1}^*	$V_{CE} = 5.0\text{ V}$, $I_C = 0.5\text{ A}$	20		80	
DC current gain	h_{FE2}^*	$V_{CE} = 5.0\text{ V}$, $I_C = 2.0\text{ A}$	10			
Collector saturation voltage	$V_{CE(sat)}^*$	$I_C = 2.0\text{ A}$, $I_B = 0.4\text{ A}$			1.0	V
Base saturation voltage	$V_{BE(sat)}^*$	$I_C = 2.0\text{ A}$, $I_B = 0.4\text{ A}$			1.2	V
Turn-on time	t_{on}	$I_C = 2.0\text{ A}$, $R_L = 75\text{ }\Omega$, $I_{B1} = -I_{B2} = 0.4\text{ A}$, $V_{CC} \equiv 150\text{ V}$ Refer to the test circuit.			1.0	μs
Storage time	t_{stg}				2.0	μs
Fall time	t_f				0.7	μs

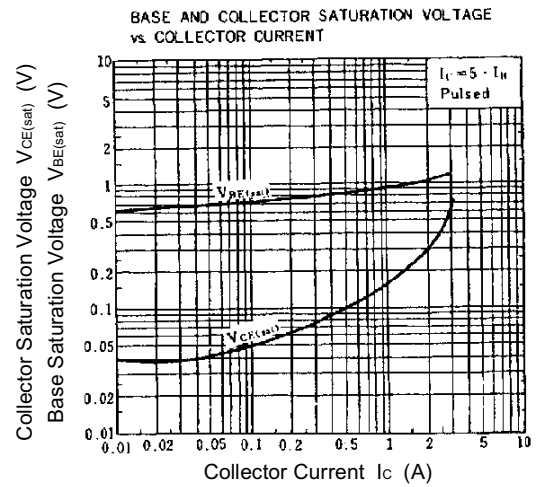
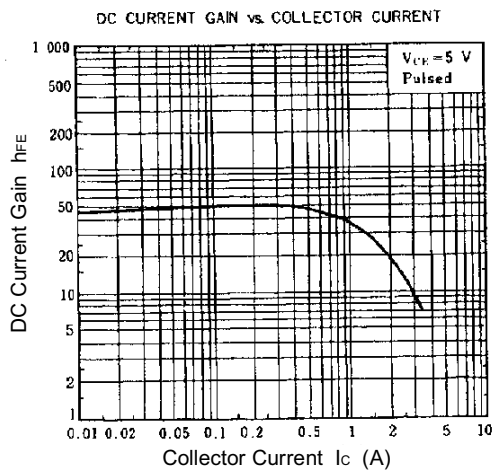
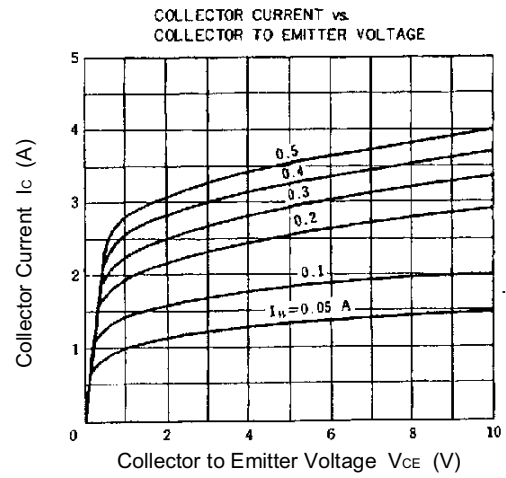
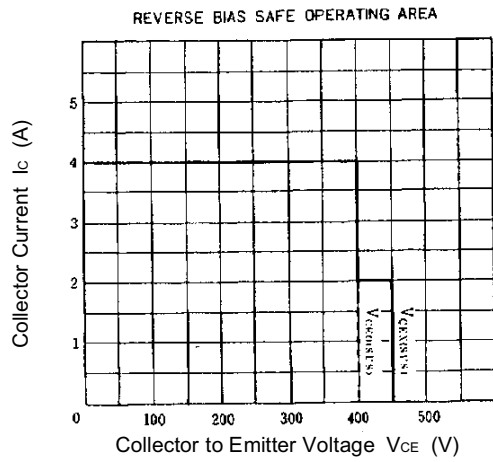
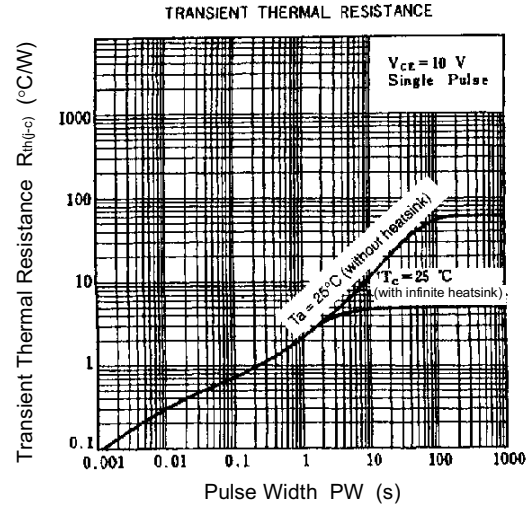
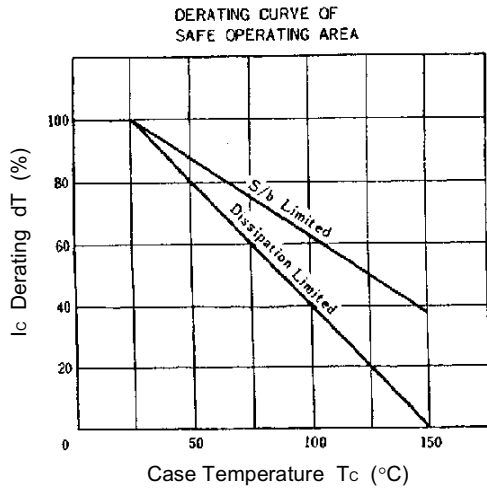
* Pulse test $PW \leq 350\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

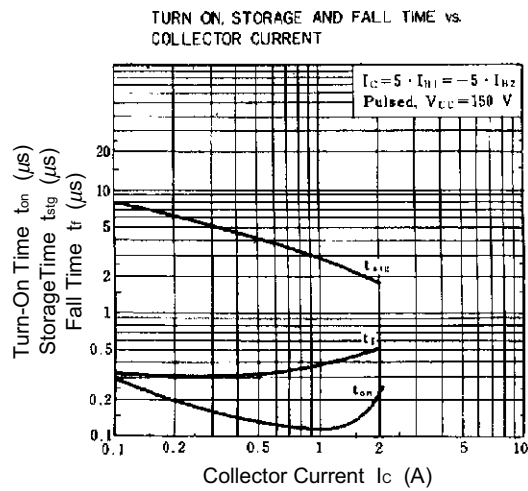
h_{FE} CLASSIFICATION

Marking	M	L	K
h_{FE1}	20 to 40	30 to 60	40 to 80

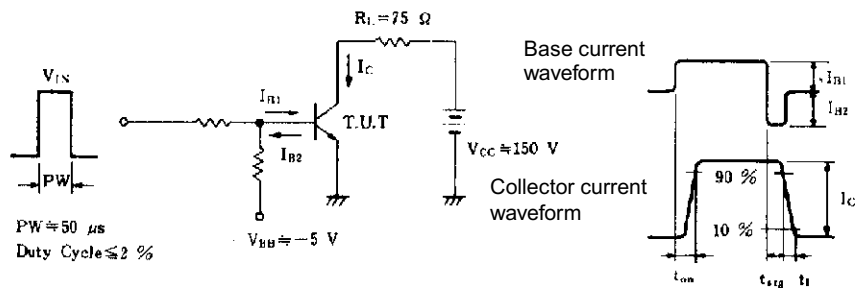
TYPICAL CHARACTERISTICS (Ta = 25°C)







SWITCHING TIME (t_{on} , t_{stg} , t_r) TEST CIRCUIT



[MEMO]

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